

AM4951/R/2

General Description

The AM4951/R/2 series is a single-phase BTL output fan motor driver designed by bipolar process. This IC features high efficiency, silent operation and includes lock shutdown and automatic restart functions. When the motor is under lock condition, the lock shutdown function turns off the output current. When the lock condition is removed, the IC will restart automatically and allow DC fan to run. It is applied for high reliability and low noise application, such as personal computers, notebook, car audio, CPU cooling systems and power supplies in consumer electronics systems.

The AM4951/R series is available in MSOP-8 (12V application only) or PSOP-8 (24V application only) package. The AM4952 is available in MSOP-10 package.

Features

- BTL Output Single-phase Full-wave Linear Drive (Gain Resistor=1k to 360kΩ, Gain=51dB)
- Support Low-voltage Drive and Feature a Wide Usable Voltage Range (2.2V to 24V)
- Low Saturation Output (High Side and Low Side Saturation Voltage): V_{SAT_TOTAL}=1.2V (typical, I_{OUT}=200mA)
- Built-in Lock Protection and Automatic Restart Circuits
- Built-in FG/RD Output
- Built-in Hall Sensor Bias (AM4952 Only, V_{HB}=1.5V)
- Thermal Protection Circuit
- Small-sized, High Thermal Capacity Package
- FG Output (AM4951), RD Output (AM4951R), FG and RD Output (AM4952)

Applications

- Notebook, Personal Computers
- Power Supplies in Consumer Electronics, Car Audio and Office Peripherals
- CPU Cooling Systems

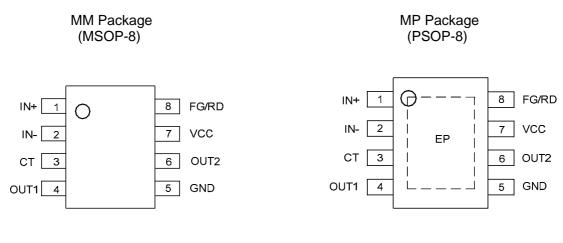


Figure 1. Package Types of AM4951/R/2



AM4951/R/2

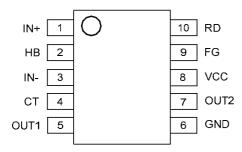
Pin Configuration



For AM4951/R 12V Application

For AM4951/R 24V Application

MM Package (MSOP-10)



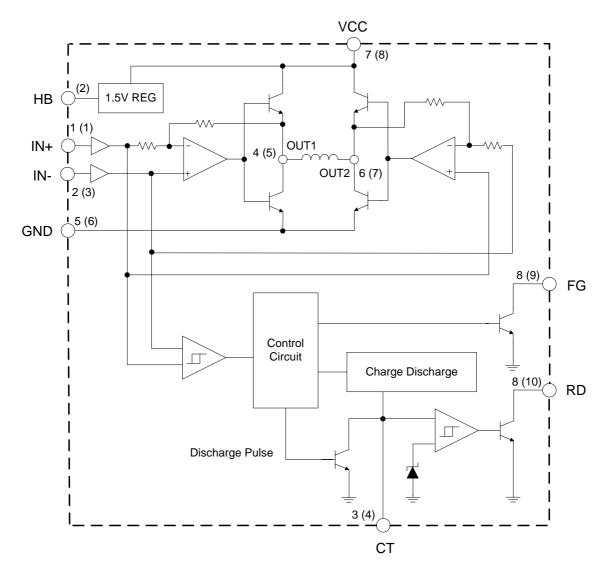
For AM4952

Figure 2. Pin Configuration of AM4951/R/2 (Top View)



AM4951/R/2

Functional Block Diagram



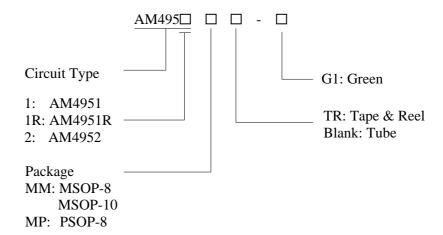
A (B) A for AM4951/R B for AM4952

Figure 3. Functional Block Diagram of AM4951/R/2



AM4951/R/2

Ordering Information



Package	Temperature Range	Output Signal	Part Number	Marking ID	Packing Type	
MSOP-8	FG RD -40 to 105°C FG RD FG & RD	FG	AM4951MM-G1	4951MM-G1	Tube	
			AM4951MMTR-G1	4951MM-G1	Tape & Reel	
		RD	AM4951RMM-G1	4951RMM-G1	Tube	
			AM4951RMMTR-G1	4951RMM-G1	Tape & Reel	
PSOP-8		FG	AM4951MP-G1	4951MP-G1	Tube	
			AM4951MPTR-G1	4951MP-G1	Tape & Reel	
		RD	AM4951RMP-G1	4951RMP-G1	Tube	
			AM4951RMPTR-G1	4951RMP-G1	Tape & Reel	
MSOP-10		EC & DD	AM4952MM-G1	4952MM-G1	Tube	
		FG & RD	AM4952MMTR-G1	4952MM-G1	Tape & Reel	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



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Absolute Maximum Ratings (Note 1, T_A=25°C)

Parameter	Symbol	Value		Unit
Supply Voltage	V _{CC}	28		V
Peak Output Current	I_{OUT}	500		mA
FG/RD Pull-up Voltage	V_{FG}/V_{RD}	28		V
FG/RD Output Current	I_{FG}/I_{RD}	10		mA
		MSOP-8	205	
Thermal Resistance (Junction to Ambient)	$ heta_{ m JA}$	PSOP-8	110	°C/W
(Junetion to Timolent)		MSOP-10	195	
		MSOP-8	48	
Thermal Resistance (Junction to Case)	$ heta_{ m JC}$	PSOP-8	36	°C/W
(Junetion to Cuse)		MSOP-10	46	
		MSOP-8	585	mW
Power Dissipation	P_{D}	PSOP-8	960	mW
		MSOP-10	585	mW
Operating Temperature	T_{OP}	-40 to 125		°C
Storage Temperature	T_{STG}	-55 to 150		°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit	
Supply Voltage	V_{CC}	2.2	24	V	
Hall Input Voltage	V_{ICM}	0	V _{CC} -1.5	V	
Operating Ambient Temperature	T_{A}	-40	105	°C	



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Electrical Characteristics

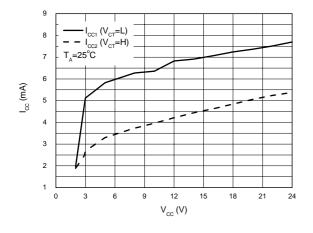
 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Sweets Comment	I_{CC1}	V _{CT} =L	3	6	9	mA
Supply Current	I_{CC2}	V _{CT} =H	2.5	5	7.5	mA
CT Charge Current	I_{CHG}		0.9	1.3	1.5	μΑ
CT Discharge Current	I_{DHG}		0.1	0.15	0.25	μΑ
CT Charge/Discharge Current Ratio	R _{CT}	I _{CHG} / I _{DHG}	6	8	10	
CT Clamp Voltage	V_{CL}		1.3	1.5	1.7	V
CT Comparator Voltage	V _{CP}		0.3	0.5	0.7	V
OUT Low Saturation Voltage	V _{SAT_L}	I _{OUT} =200mA		0.25	0.45	V
OUT High Saturation Voltage	V _{SAT_H}	I _{OUT} =200mA		0.95	1.2	V
Hall Input Sensitivity	V _{HN}			7	15	mV
FG Low Level Voltage (For AM4951/2)	V_{FG}	I _{FG} =5mA		0.15	0.3	V
FG Leakage Current (For AM4951/2)	I_{FGL}	V _{FG} =15V		1	30	μΑ
RD Low Level Voltage (For AM4951R/2)	V_{RD}	I _{RD} =5mA		0.15	0.3	V
RD Leakage Current (For AM4951R/2)	I_{RDL}	V _{RD} =15V		1	30	μΑ
HB Voltage (For AM4952)	V_{HB}	I _{HB} =1mA	1.35	1.5	1.65	V



AM4951/R/2

Typical Performance Characteristics



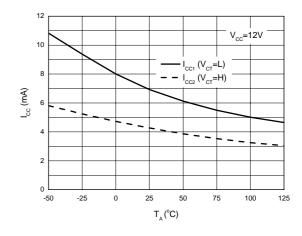
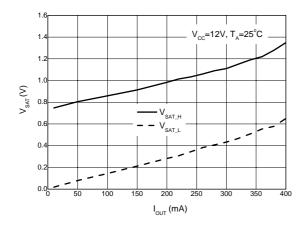


Figure 4. Supply Current vs. Supply Voltage

Figure 5. Supply Current vs. Ambient Temperature



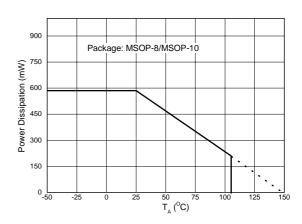


Figure 6. Saturation Voltage vs. Output Current

Figure 7. Power Dissipation vs. Ambient Temperature



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Typical Performance Characteristics (Continued)

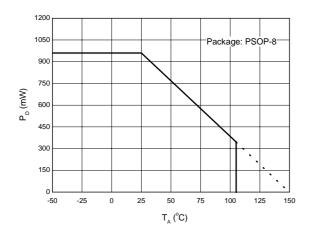
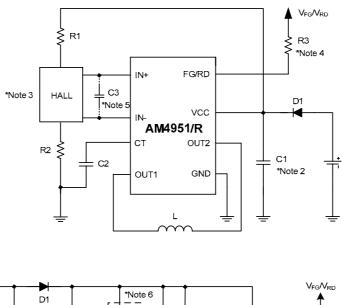


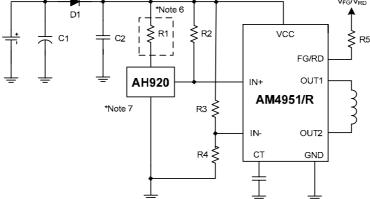
Figure 8. Power Dissipation vs. Ambient Temperature



AM4951/R/2

Typical Application





Note 2: Adding D1 can protect the IC from destruction by reverse connection. If D1 is used, it is necessary to insert a capacitor C1 to provide a regenerative current route. Similarly, if there is no nearby capacitor on the fan power supply line, C1 will also be necessary to improve reliability. Its capacity should be larger than $2.2\mu F$.

Note 3: If the Hall sensor bias is taken from V_{CC} , A 1/2 V_{CC} bias, as shown in the figure must be used. Adjusting the value of R1 and R2 may achieve better startup characteristics and efficiency, even quiet operation.

Note 4: This pin must be left open if unused.

Note 5: If the line between Hall sensor output and Hall sensor input of IC is long, the noise may occur in this line. But it can be eliminated by adding a capacitor C3.

Note 6: Each of R2, R3, R4 and R5 (AM4951/R only) is recommended to be $51k\Omega$ typical. R1 is recommended to be 2k and must be added when V_{CC} is larger than 20V.

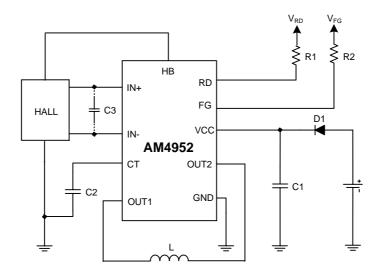
Note 7: The package of AH920 is SOT-23-3. If it is packaged in TO-92S-3, please exchange IN- with IN+.

Figure 9. Typical Application of AM4951/R



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Typical Application (Continued)



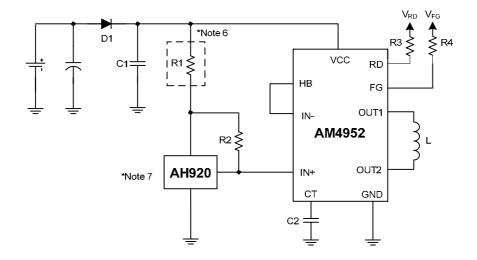


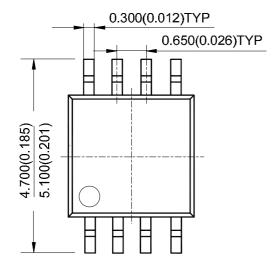
Figure 10. Typical Application of AM4952

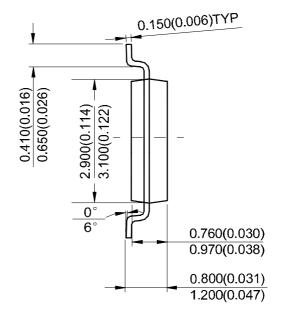


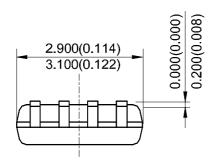
AM4951/R/2

Mechanical Dimensions

MSOP-8 Unit: mm(inch)







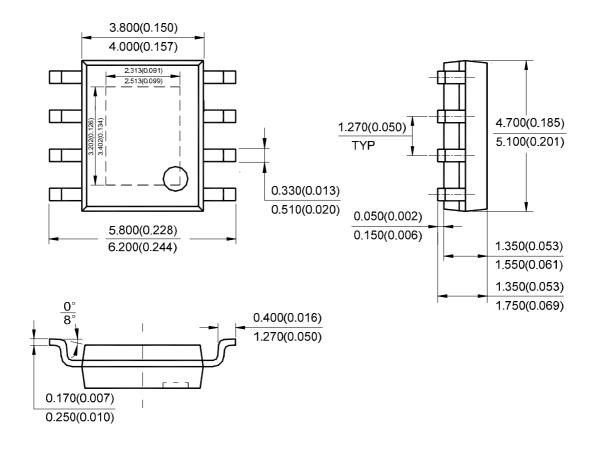
Note: Eject hole, oriented hole and mold mark is optional.



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Mechanical Dimensions (Continued)

PSOP-8 Unit: mm(inch)



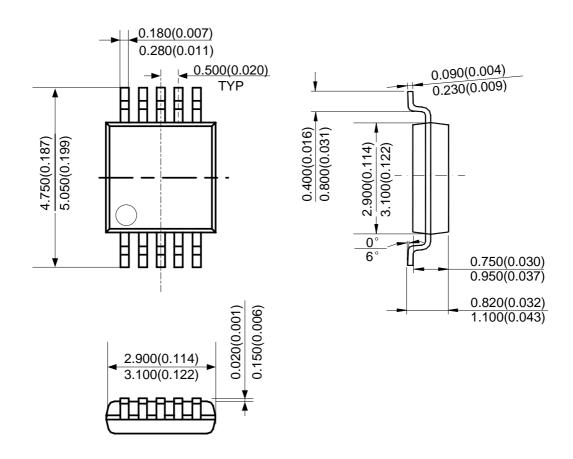
Note: Eject hole, oriented hole and mold mark is optional.



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Mechanical Dimensions (Continued)

MSOP-10 Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.





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